



P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

| V _{(BR)DSS} | R _{DS(ON)} max | I _D max T _A = +25°C |
|----------------------|---------------------------------|--|
| 2014 | 75mΩ @ V _{GS} = -4.5V | -3.3A |
| -20V | 140mΩ @ V _{GS} = -1.8V | -2.4A |

Description and Applications

This MOSFET has been designed to minimize the on-state resistance (R_{DS(on)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- **Battery Charging**
- **Power Management Functions**
- **DC-DC Converters**
- Portable Power Adaptors

Features and Benefits

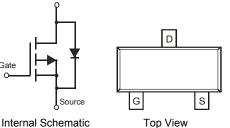
- Low On-Resistance
- Very Low Gate Threshold Voltage V_{GS(th)} ≤ 1V
- Low Input Capacitance
- Fast Switching Speed •
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q 101 Standards for High Reliability

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram Below
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.008 grams (approximate)



Top View



Ordering Information (Note 4)

| Part Number | Case | Packaging |
|-------------|-------|------------------|
| DMP2160U-7 | SOT23 | 3000/Tape & Reel |

Drair

Gate

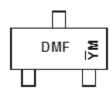
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

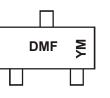
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information





DMF = Marking Code YM = Date Code Marking for SAT (Shanghai Assembly/ Test site) YM = Date Code Marking for CAT (Chengdu Assembly/ Test site) Y or \overline{Y} = Year (ex: A = 2013) M = Month (ex: 9 = September)

Chenadu A/T Site

Shanghai A/T Site

Date Code Key

Notes:

| Year | 2008 | | 2009 | 2010 | | 2011 | 2012 | | 2013 | 2014 | | 2015 |
|-------|------|-----|------|------|-----|------|------|-----|------|------|-----|------|
| Code | V | | W | Х | | Y | Z | | А | В | | С |
| Month | Jan | Feb | Mar | Apr | Мау | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D |



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Units | |
|--|--|-----------------|--------------|---|
| Drain-Source Voltage | V _{DSS} | -20 | V | |
| Gate-Source Voltage | V _{GSS} | ±12 | V | |
| Continuous Drain Current (Note 5) V_{GS} = -4.5V | T _A = +25°C T _A = +70°C | ID | -3.3 -2.6 | A |
| Pulsed Drain Current | | I _{DM} | -13 | А |

Thermal Characteristics

| Characteristic | Symbol | Value | Units |
|--|----------------------------------|-------------|-------|
| Total Power Dissipation (Note 5) | PD | 1.4 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | R _{0JA} | 90 | °C/W |
| Thermal Resistance, Junction to Case (Note 5) | R _{θJC} | 22 | °C/W |
| Operating and Storage Temperature Range | T _{J,} T _{STG} | -55 to +150 | °C |

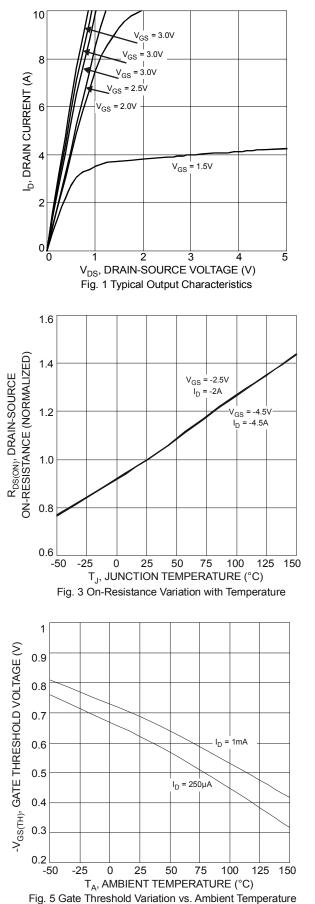
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| | | | _ | | | |
|--|----------------------|------|------|------|------|---|
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
| OFF CHARACTERISTICS (Note 6) | - | 1 | 1 | 1 | r | 1 |
| Drain-Source Breakdown Voltage | BV _{DSS} | -20 | — | — | V | $V_{GS} = 0V, I_D = -250\mu A$ |
| Zero Gate Voltage Drain Current T _J = +25°C | IDSS | | | -1.0 | μA | V_{DS} = -16V, V_{GS} = 0V |
| Gate-Source Leakage | 1 | — | — | ±100 | nA | V_{GS} = ±8V, V_{DS} = 0V |
| Gale-Source Leakage | I _{GSS} | — | — | ±800 | ПА | V_{GS} = ±12V, V_{DS} = 0V |
| ON CHARACTERISTICS (Note 6) | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | -0.4 | -0.6 | -0.9 | V | $V_{DS} = V_{GS}, I_D = -250 \mu A$ |
| | | | 60 | 75 | | V _{GS} = -4.5V, I _D = -1.5A |
| Static Drain-Source On-Resistance | R _{DS (ON)} | — | 73 | 96 | mΩ | V _{GS} = -2.5V, I _D = -1.2A |
| | | | 92 | 140 | | V _{GS} = -1.8V, I _D = -1.2A |
| Forward Transconductance | g fs | | 7 | _ | S | V _{DS} = -10V, I _D = -1.5A |
| Diode Forward Voltage (Note 5) | V _{SD} | | | -1.0 | V | V _{GS} = 0V, I _S = -1.0A |
| DYNAMIC CHARACTERISTICS (Note 7) | | | | | | |
| Input Capacitance | Ciss | | 627 | | pF | <u> </u> |
| Output Capacitance | Coss | | 64 | | pF | −V _{DS} = -10V, V _{GS} = 0V −f = 1.0MHz |
| Reverse Transfer Capacitance | C _{rss} | _ | 53 | _ | pF | |
| Gate Resistance | R _G | | 44.9 | | Ω | $V_{GS} = 0V, V_{DS} = 0V, f = 1.0MHz$ |
| Total Gate Charge | Qg | | 6.5 | | nC | |
| Gate-Source Charge | Q _{gs} | _ | 0.9 | _ | nC | V _{GS} = -4.5V, V _{DS} = -10V, I _D = -3A |
| Gate-Drain Charge | Q _{gd} | _ | 1.5 | _ | nC | |
| Turn-On Delay Time | t _{D(on)} | | 12.5 | _ | ns | |
| Turn-On Rise Time | tr | | 10.3 | | ns | V _{DS} = -10V, V _{GS} = -4.5V, |
| Turn-Off Delay Time | t _{D(off)} | _ | 46.5 | _ | ns | $R_L = 10\Omega, R_G = 1.0\Omega, I_D = -1A$ |
| Turn-Off Fall Time | t _f | | 22.2 | | ns | |

5. Device mounted on $1in^2$ FR-4 PCB with 2 oz. Copper. t ≤ 10 sec. Notes:

6. Short duration pulse test used to minimize self-heating effect.7. Guaranteed by design. Not subject to product testing.





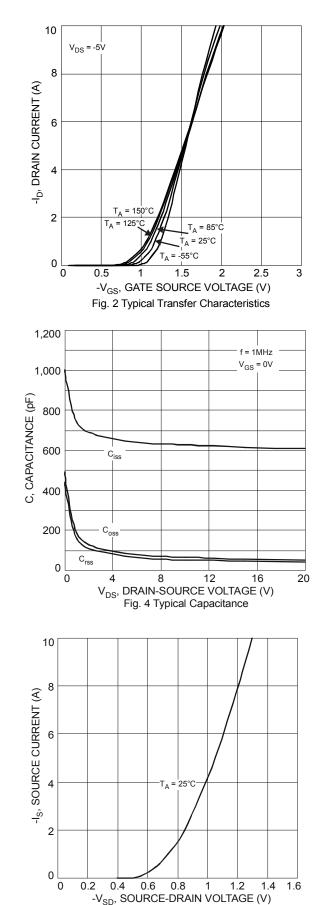
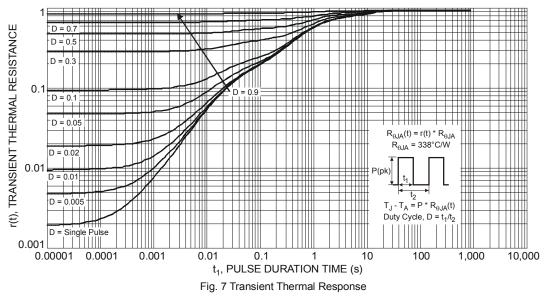


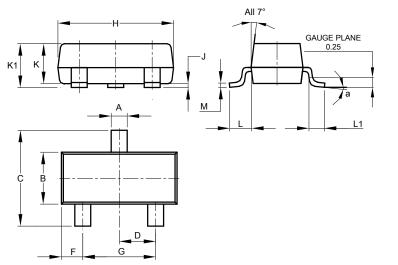
Fig. 6 Diode Forward Voltage vs. Current





Package Outline Dimensions

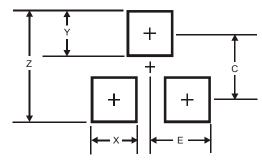
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



| SOT23 | | | | | | |
|----------------------|-------|-------|-------|--|--|--|
| Dim | Min | Max | Тур | | | |
| Α | 0.37 | 0.51 | 0.40 | | | |
| В | 1.20 | 1.40 | 1.30 | | | |
| С | 2.30 | 2.50 | 2.40 | | | |
| D | 0.89 | 1.03 | 0.915 | | | |
| F | 0.45 | 0.60 | 0.535 | | | |
| G | 1.78 | 2.05 | 1.83 | | | |
| Н | 2.80 | 3.00 | 2.90 | | | |
| ر | 0.013 | 0.10 | 0.05 | | | |
| κ | 0.890 | 1.00 | 0.975 | | | |
| K1 | 0.903 | 1.10 | 1.025 | | | |
| L | 0.45 | 0.61 | 0.55 | | | |
| L1 | 0.25 | 0.55 | 0.40 | | | |
| М | 0.085 | 0.150 | 0.110 | | | |
| α | 8° | | | | | |
| All Dimensions in mm | | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 2.9 |
| Х | 0.8 |
| Y | 0.9 |
| С | 2.0 |
| E | 1.35 |



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